

DIODE(THREE PHASES BRIDGE TYPE)

DF40BA40/80

TOP



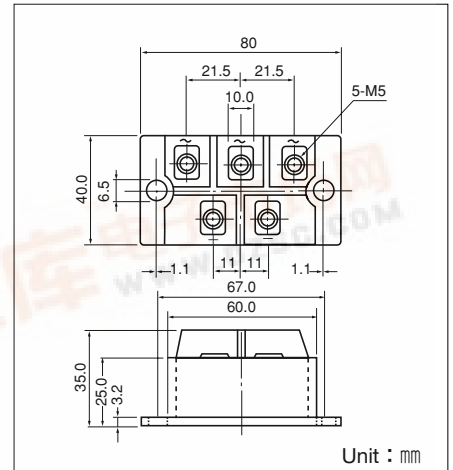
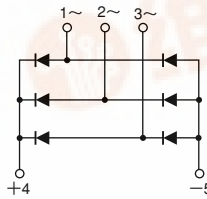
UL;E76102 (M)

Power Diode Module **DF40BA** is designed for three phase full wave rectification, which has six diodes connected in a three phase bridge configuration. The mounting base of the module is electrically isolated from semiconductor elements for simple heatsink construction output DC current is 40Amp ($T_c=119^{\circ}\text{C}$) Repetitive peak reverse voltage is up to 800V.

- $T_{j\text{Max}}=150^{\circ}\text{C}$
- Isolated Mounting Base
- High reliability by unique glass passivation

(Applications)

AC. DC Motor Drive/AVR/Switching
—for three phase rectification



Maximum Ratings

(T_j=25°C unless otherwise specified)

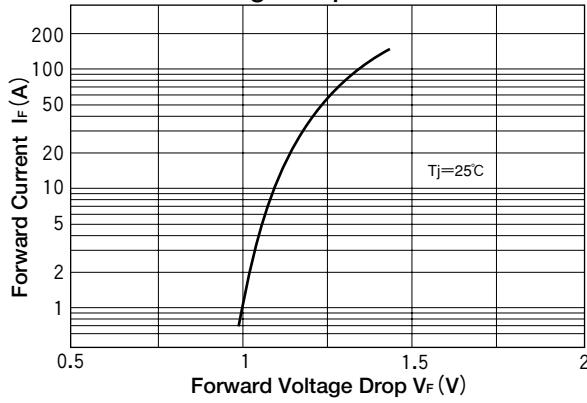
Symbol	Item	Ratings		Unit
		DF40BA40	DF40BA80	
V _{RRM}	Repetitive Peak Reverse Voltage	400	800	V
V _{RSM}	Non-Repetitive Peak Reverse Voltage	480	960	V

Symbol	Item		Conditions	Ratings	Unit
I _D	Output current (D.C.)		Three phase. full wave. T _c =119°C	40	A
I _{FSM}	Surge Forward Current		1 cycle, 50/60Hz, peak value, non-repetitive	640/700	A
T _j	Junction Temperature			-40 to +150	°C
T _{stg}	Storage Temperature			-40 to +125	°C
V _{ISO}	Isolation Breakdown Voltage (R.M.S.)		Main Terminal to case 1minute	2500	V
	Mounting Torque	Mounting (M6)	Recommended Value 2.5-3.9 (25-40)	4.7 (48)	N·m (kgf·cm)
		Terminal (M5)	Recommended Value 1.5-2.5 (15-25)	2.7 (28)	
	Mass		Typical Value	200	g

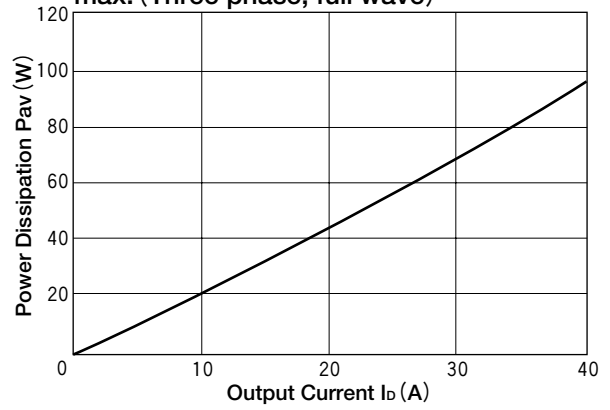
Electrical Characteristics

Symbol	Item	Conditions	Ratings	Unit
I _{RRM}	Repetitive Peak Reverse Current, max.	T _j =150°C at V _{RRM}	4.0	mA
V _{FM}	Forward Voltage Drop, max.	I _{FM} =40A, T _j =25°C Inst. measurement	1.2	V
R _{th(j-c)}	Thermal Impedance, max.	Junction to case	0.32	°C/W

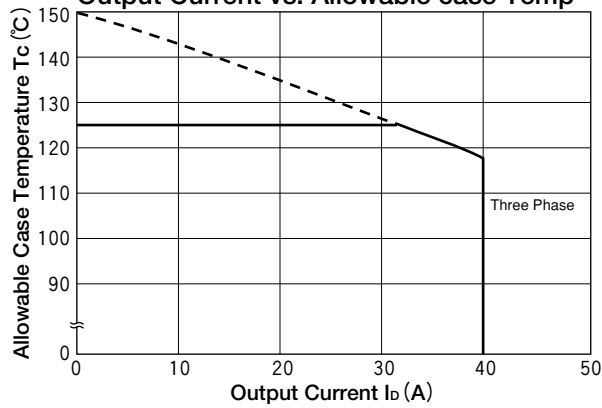
Forward Voltage Drop max.



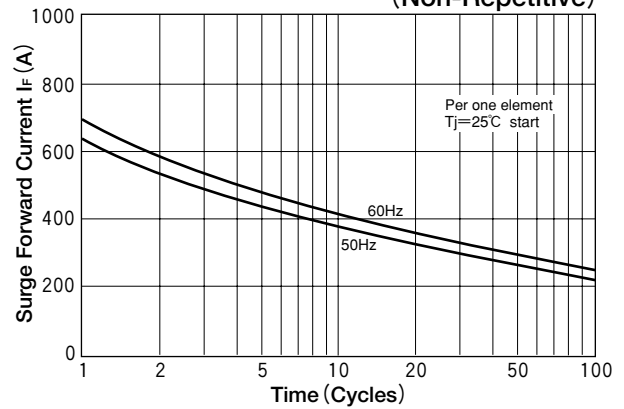
Output Current vs. Power Dissipation, max. (Three phase, full wave)



Output Current vs. Allowable case Temp



Cycle Surge Forward Current Rating (Non-Repetitive)



Transient Thermal Impedance (max)

